

Features

- Bidirectional TVS 5 V
- ESD protection >15 kV
- Replacement for MLV (0402)
- Low capacitance 3.0 pF
- Low Leakage Current

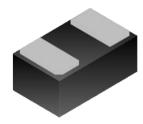
Applications

- Mother Board and Notebook, Cellular Phone, Set-Top Box etc.
- Suitable for USB2.0, TF Card Line and high Frequency single line over voltage protect

VTSB53W3 ----- SURFACE MOUNT TVS Diodes

General Information

The VTSB53W3 is designed with Vicsemi Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Maximum Contact discharge voltage Per IEC61000-4-2		8KV	V
Maximum Air discharge voltage Per IEC61000-4-2		15KV	V
Maximum Operating temperature	T _{OPER}	-40 to +90	℃
Maximum Storage temperature	T_{STG}	-55 to +125	℃
Maximum lead temperature for soldering during 10s	T_L	260	℃

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Working Voltage	V_{RWM}	Any I/O pin to GND			5	V
Reverse Breakdown Voltage	V_{BR}	Any I/O pin to GND I_T =1mA	6			V
Positive Clamping Voltage	V_{C}	I _{PP} =1A, t _P =8/20μ; Any I/O pin to GND		9.5	12	٧
Peak Pulse Current	${ m I}_{ m PP}$	t _p =8/20μs waveform			6	А
Reverse Leakage Current	${ m I}_{\sf L}$	V _{RWM} =5V ; Any I/O pin to GND			1.00	uA
Junction Capacitance	C _P	V _R =0V, f=1MHz; Any I/O pin to GND		3.0		pF



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Typical Protection Circuit

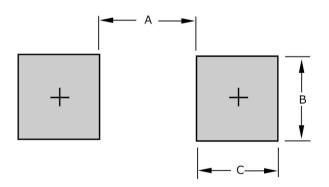
Protected Devices

Block Diagram



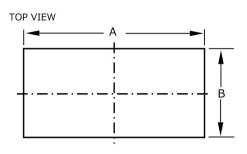
Bi-directional

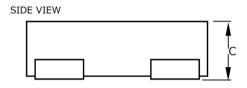
Recommended PCB Footprint

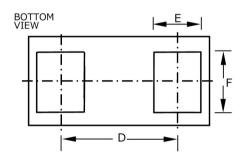


Dimension	DFN-2L
А	<u>0.30</u> (0.012)
В	<u>0.80</u> (0.031)
С	<u>0.55</u> (0.022)

Product Dimensions







Dimension	DFN-2L
А	<u>0.95-1.05</u> (0.037-0.041)
В	<u>0.55-0.65</u> (0.022-0.026)
С	<u>0.40-0.50</u> (0.016-0.020)
D	<u>0.65</u> (0.026)
E	<u>0.10-0.35</u> (0.004-0.014)
F	0.40-0.50 (0.016-0.020)

DIMENSIONS: MM (INCHES)



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Performance Graphs

Figure 1: Power Derating Curve

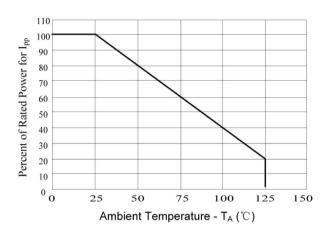


Figure 2: Insertion Loss

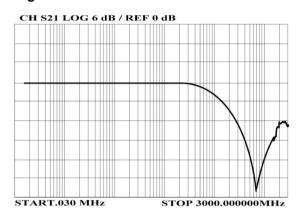


Figure 3: Normalized Junction Capacitance vs. Reverse Voltage

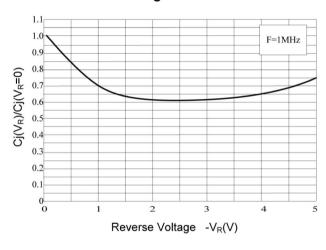


Table 1. IEC 61000-4-2 Discharge Parameters

Level	First Peak Current (A)	Peak Current at 30 ns (A)	Peak Current at 60 ns (A)	Test Voltage (Contact Discharge) (kV)	Test Voltage (Air Discharge) (kV)
1	7.5	4	2	2	2
2	15	8	4	4	4
3	22.5	12	6	6	8
4	30	16	8	8	15

Figure 4. IEC 61000-4-2 Waveform

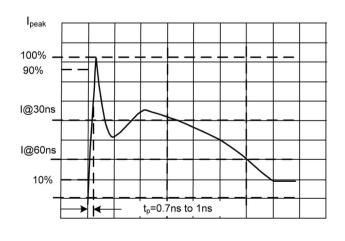
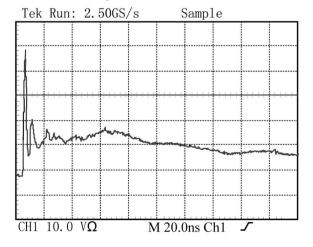


Figure 5: ESD Clamping(8kV Contact per IEC 61000-4-2)

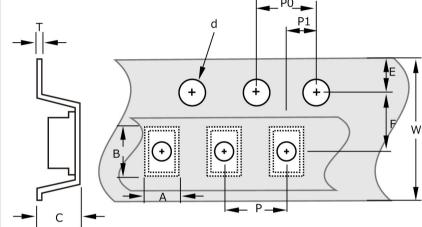


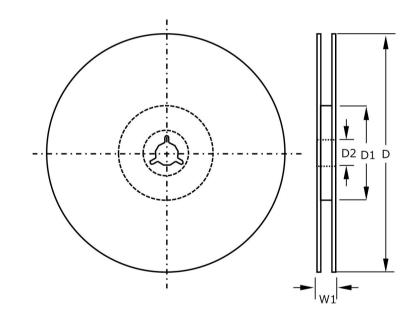


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Packaging Information

Symbol	DFN-2L
А	0.7±0.05 (0.028±0.002)
В	1.15±0.05 (0.045±0.002)
С	0.47±0.05 (0.019±0.002)
d	1.55±0.05 (0.061±0.002)
D	180.00±2.00 (7.087±0.079)
D1	60.0±1.00 (2.362±0.039)
D2	13.0±0.20 (0.516±0.008)
E	1.75±0.10 (0.069±0.004)
F	3.50±0.05 (0.138±0.002)
Р	$\frac{2.00\pm0.10}{(0.079\pm0.004)}$
P0	4.00±0.10 (0.157±0.004)
P1	2.00±0.05 (0.079±0.002)
Т	0.20±0.05 (0.008±0.002)
W	8.00±0.10 (0.315±0.004)
W1	11.6±1.00 (0.457±0.039)





DIMENSIONS: MM (INCHES)

Quantity of products in the taping package

- (1) Standard quantity: 5000 pcs/reel or 10000 pcs/Reel for the Series.
- (2) Shipping quantity is a multiple of standard quantity.
- (3) For additional information, please contact your local Sales Representative.